

isc N-Channel Mosfet Transistor

10N12

• FEATURES

- Drain Current $-I_D = 10A @ T_C = 25^\circ C$
- Drain Source Voltage- : $V_{DSS} = 120V (Min)$
- Static Drain-Source On-Resistance : $R_{DS(on)} = 0.3 \Omega (Max)$
- SOA is Power-Dissipation Limited
- Nanosecond Switching Speeds
- High Input Impedance
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• DESCRIPTION

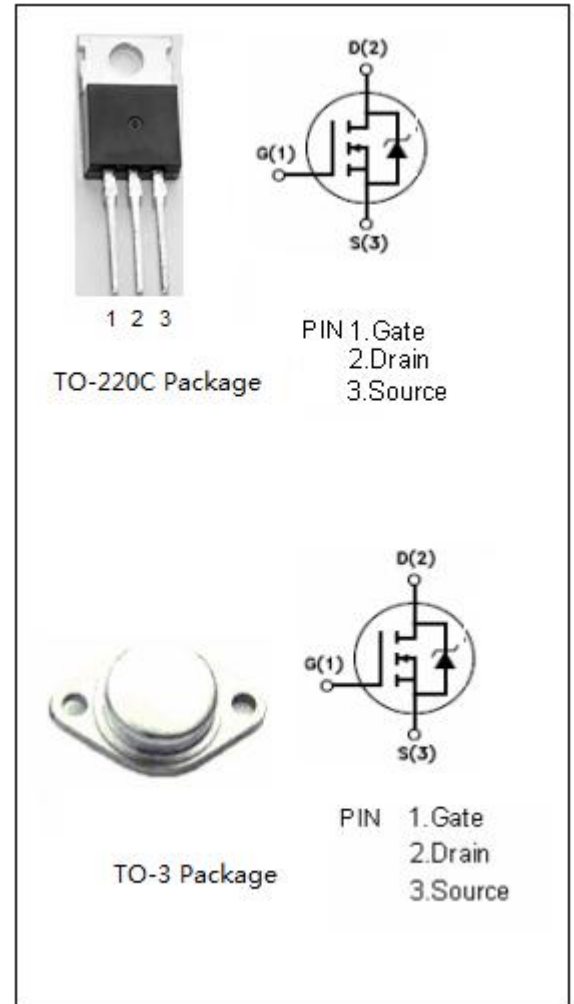
- Designed for switching converters, motor drivers, relay drivers

• ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	120	V
V_{GS}	Gate-Source Voltage-Continuous	± 20	V
I_D	Drain Current-Continuous	10	A
I_{DM}	Drain Current-Single Pulsed	25	A
P_D	Total Dissipation @ $T_C = 25^\circ C$	75	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	0.6	$^\circ C/W$



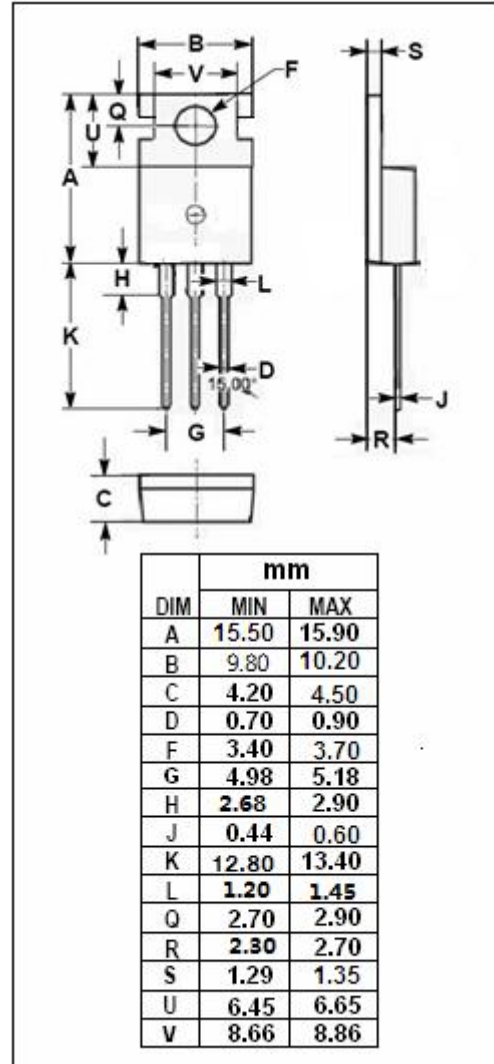
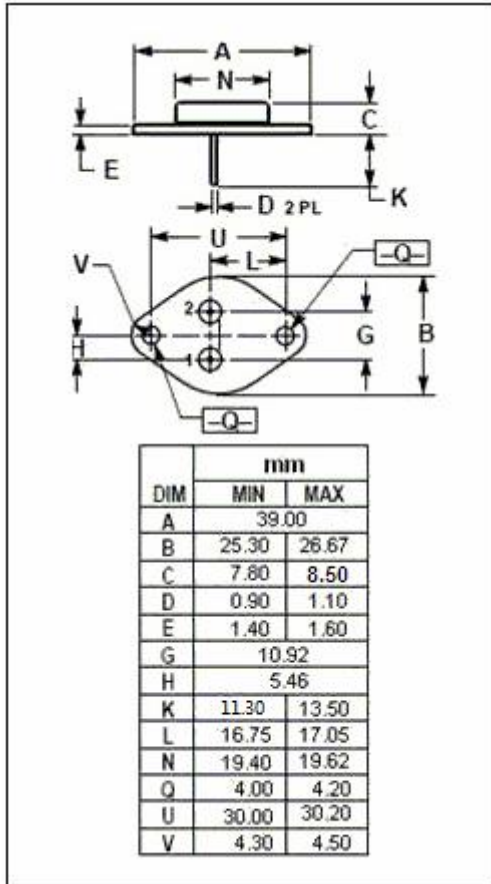
isc N-Channel Mosfet Transistor**10N12****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	$V_{GS}=0$; $I_D=1\text{mA}$	120		V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$; $I_D=2\text{mA}$	2	4	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10\text{V}$; $I_D=5\text{A}$		0.3	Ω
I_{GSS}	Gate-Body Leakage Current	$V_{GS}=\pm 20\text{V}$; $V_{DS}=0$		± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=120\text{V}$; $V_{GS}=0$ $V_{DS}=120\text{V}$; $V_{GS}=0$; $T_C=125^{\circ}\text{C}$		1 50	μA
V_{SD}	Forward On-Voltage	$I_S=5\text{A}$; $V_{GS}=0$		1.4	V

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Outline Drawing



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